TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM6N17FU

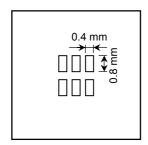
High Speed Switching Applications Analog Switch Applications

- · Suitable for high-density mounting due to compact package
- High drain-source voltage
- High speed switching

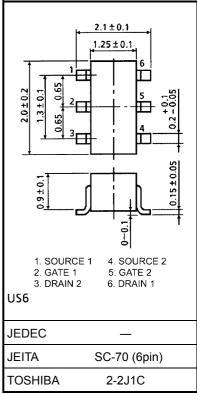
Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V_{DS}	50	V	
Gate-Source voltage		V_{GSS}	±7	V	
Drain current	DC	I _D	100	mA	
	Pulse	I _{DP}	200		
Drain power dissipation (Ta = 25°C)		P _D (Note)	200	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Note: Total rating, Mounted on FR4 board (25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 0.32 mm² × 6)



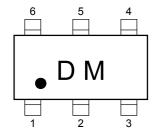
Unit: mm

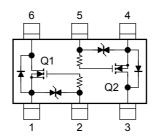


Weight: 6.8 mg (typ.)

Marking

Equivalent Circuit





1

This transistor is a electrostatic sensitive device. Please handle with caution.

Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

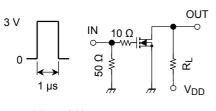
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	V _{GS} = ±7 V, V _{DS} = 0	_	_	±5	μΑ
Drain-Source breakdown voltage		V (BR) DSS	I _D = 0.1 mA, V _{GS} = 0	50	_	_	V
Drain cut-off currer	nt	I _{DSS}	V _{DS} = 50 V, V _{GS} = 0	_	_	1	μΑ
Gate threshold vol	tage	V _{th}	V _{DS} = 3 V, I _D = 1 μA	0.9	_	1.5	V
Forward transfer admittance		Y _{fs}	V _{DS} = 3 V, I _D = 10 mA	20	40	_	mS
Drain-Source ON resistance		R _{DS (ON)}	I _D = 10 mA, V _{GS} = 4 V	_	12	20	Ω
			I _D = 10 mA, V _{GS} = 2.5 V	_	22	40	
Input capacitance		C _{iss}	V _{DS} = 3 V, V _{GS} = 0, f = 1 MHz	_	7	_	pF
Reverse transfer capacitance		C _{rss}		_	3	_	pF
Output capacitance		Coss		_	7	_	pF
Switching time	Turn-on time	t _{on}	V_{DD} = 3 V, I_{D} = 20 mA, V_{GS} = 0~3 V, R_{G} = 10 Ω , R_{L} = 150 Ω	_	100	_	ns
	Turn-off time	t _{off}		1	40		

Switching Time Test Circuit

(a) Test circuit

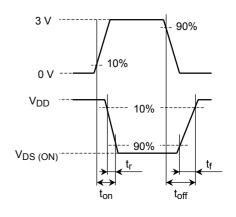
(b) V_{IN}

(c) V_{OUT}

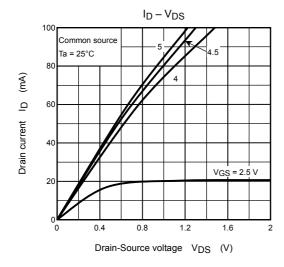


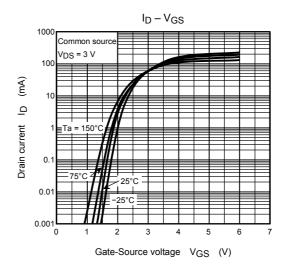
 $V_{DD} = 3 V$ Duty $\le 1\%$ V_{IN} : t_r , $t_f < 5$ ns

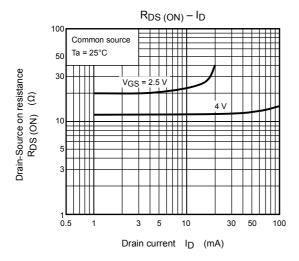
 $(Z_{\text{out}} = 50 \ \Omega)$ Common source $Ta = 25^{\circ}C$

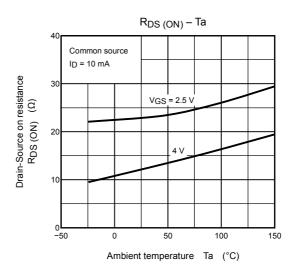


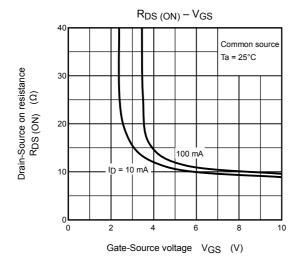
(Q1, Q2 Common)

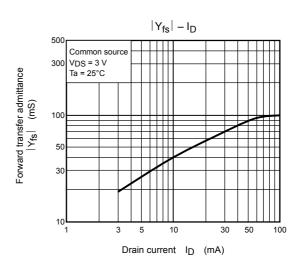






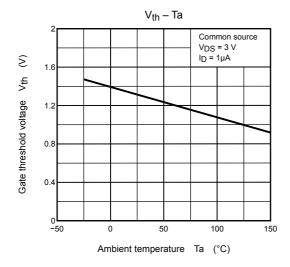


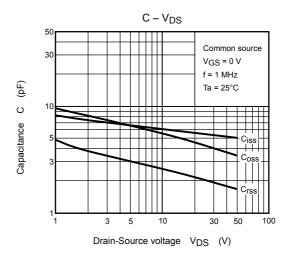


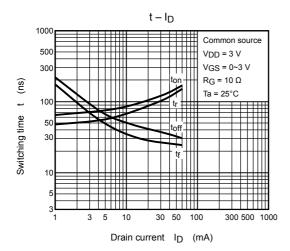


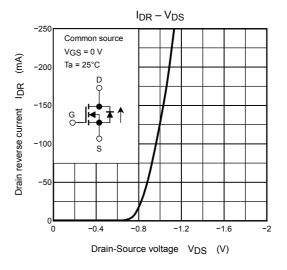
3

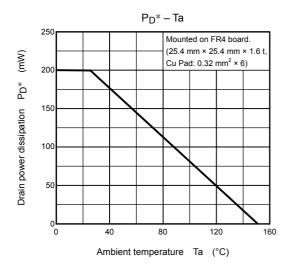
(Q1, Q2 Common)











*: Total rating

RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other
 rights of the third parties which may result from its use. No license is granted by implication or otherwise under
 any intellectual property or other rights of TOSHIBA CORPORATION or others.

5

• The information contained herein is subject to change without notice.